

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VHCV573FK

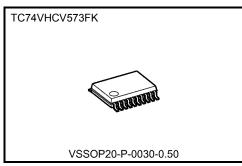
Octal Schmitt D-Type Latch with 3-State Output

The TC74VHCV573FK is an advanced high speed CMOS OCTAL LATCH with 3-STATE OUTPUT fabricated with silicon gate C²MOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This 8-bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}).

When the \overline{OE} input is high, the eight outputs are in a high impedance state. Input pin have hysteresis between the positive-going and negative-going thresholds. Thus the TC74VHCV573FK is capable of squaring up transitions of slowly changing input signals and provides an improved noise immunity. Input protection and output circuit ensure that 0 to 5.5 V can be applied to the input and output (Note) pins without regard to the supply voltage. These structure prevents device destruction due to mismatched supply and input/output voltages such as battery back up, etc.

Note: Output in off-state.



Weight VSSOP20-P-0030-0.50 : 0.03 g (typ.)

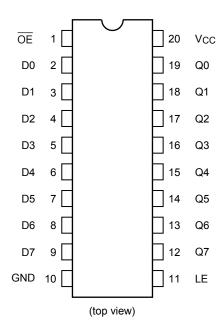
Features

- High speed: tpd = 5.0 ns (typ.) at Vcc = 5 V
- Low power dissipation: ICC = 2 μA (max) at Ta = 25°C
- Wide operating voltage range: VCC (opr) = 1.8 V to 5.5 V
- Ouput current: |IOH|/IOL = 16 mA (min) (VCC = 4.5 V)
- Available in VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 573 type

Start of commercial production 2010-01



Pin Assignment



Truth Table

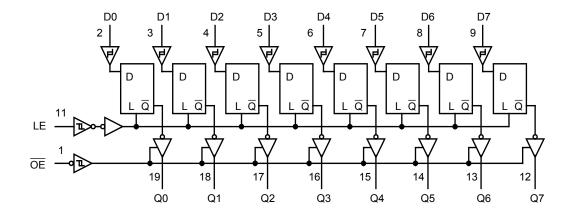
	Inputs			
ŌĒ	LE	D	Output	
Н	Х	Х	Z	
L	L	Х	Qn	
L	Н	L	L	
L	Н	Н	Н	

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram





Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	\/a	-0.5 to 7.0 (Note 2)	V
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V
Input diode current	lıK	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	ICC/IGND	±100	mA
Storage temperature	T _{stg}	−65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: Output in off-state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: VOUT < GND, VOUT > VCC

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	Vcc	1.8 to 5.5	V
Input voltage	VIN	0 to 5.5	V
Outrot wells as	Vouт	0 to 5.5 (Note 2)	
Output voltage		0 to V _{CC} (Note 3)	V
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 20 (V _{CC} = 3.3 ± 0.3V) 0 to 1 (V _{CC} = 5 ± 0.5V)	ms/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Note 2: Output in off-state

Note 3: High or low state.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
				V _{CC} (V)	Min	Тур.	Max	Min	Max	
Positive threshold voltage	VP	_		1.8 2.3 3.0 4.5 5.5	 - - -	_ _ _ _	1.65 1.85 2.20 3.15 3.85		1.65 1.85 2.20 3.15 3.85	
Negative threshold voltage	VN	_		1.8 2.3 3.0 4.5 5.5	0.15 0.45 0.90 1.35 1.65	_ _ _ _		0.15 0.45 0.90 1.35 1.65		V
Hysteresis voltage	VH	_		1.8 2.3 3.0 4.5 5.5	0.15 0.20 0.30 0.40 0.50		1.05 1.10 1.20 1.40 1.60	0.15 0.20 0.30 0.40 0.50	1.05 1.10 1.20 1.40 1.60	>
High-level output voltage	Voн	VIN = VIH or	IOH = -50 μA	1.8 3.0 4.5	1.7 2.9 4.4	1.8 3.0 4.5	 - -	1.7 2.9 4.4	 - -	
		VIL	$I_{OH} = -8 \text{ mA}$ $I_{OH} = -16 \text{ mA}$	3.0 4.5	2.58 3.94	_	_	2.48 3.80	_	
Low-level output voltage	V _{OL} =	V _{IN} = V _{IH} or	IOL = 50 μA	1.8 3.0 4.5	- - -	0.0 0.0 0.0	0.1 0.1 0.1	- - -	0.1 0.1 0.1	V
		VIL	I _{OL} = 8 mA I _{OL} = 16 mA	3.0 4.5	_	_	0.36 0.44	_	0.44 0.55	
3-state output off-state current	loz	V _{IN} = V _{IH} or V _{IL} V _{OUT} = 0 to 5.5V		1.8 to 5.5	_	_	±0.5	_	±5.0	μΑ
Power-off leakage current	IOFF	$V_{IN}/V_{OUT} = 5.5 V$		0	1	_	0.5	_	5.0	μΑ
Input leakage current	I _{IN}	V _{IN} = 5.5	V or GND	0 to 5.5	1	_	±0.1	-	±1.0	μΑ
Quiescent supply current	Icc	V _{IN} = V _C	C or GND	5.5	_	_	2.0	_	20.0	μА



Timing Requirements (input: tr = tf = 3 ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 to 85°C	Unit
			V _{CC} (V)	Тур.	Limit	Limit	
Minimum pulse width			2.5 ± 0.2	_	6.5	6.5	
(LE)	tw (H)	_	3.3 ± 0.3	_	5.0	5.0	ns
(CL)			5.0 ± 0.5	_	5.0	5.0	
			2.5 ± 0.2	_	5.0	5.0	
Minimum set-up time	t _S	_	3.3 ± 0.3	_	3.5	3.5	ns
			5.0 ± 0.5	_	3.5	3.5	
			2.5 ± 0.2	_	2.0	2.0	
Minimum hold time	th	_	3.3 ± 0.3	_	1.5	1.5	ns
			5.0 ± 0.5	I	1.5	1.5	



AC Characteristics (input: tr = tf = 3 ns)

Characteristics	Symbol	Tes	Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit
	-,		V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
			2.5 ± 0.2	15	_	8.9	16.2	1.0	19.0	
				50	_	11.8	19.1	1.0	23.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	15	_	6.6	11.9	1.0	14.0	
(LE-Q)	t_{pHL}	_	3.3 ± 0.3	50	_	8.8	15.4	1.0	17.5	ns
			5.0 ± 0.5	15	_	5.0	7.7	1.0	9.0	
			5.0 ± 0.5	50	_	6.6	9.7	1.0	11.0	
			25.02	15	_	10.4	15.8	1.0	18.0	
			2.5 ± 0.2	50	_	13.2	20.7	1.0	23.5	
Propagation delay time	t _{pLH}		22.02	15	_	7.5	11.0	1.0	13.0	20
(D-Q)	t _{pHL}	_	3.3 ± 0.3	50	_	9.5	14.5	1.0	16.5	ns
			5.0 ± 0.5	15	_	5.4	6.8	1.0	8.0	
				50	_	7.0	8.8	1.0	10.0	
	^t pZL tpZH	R _L = 1 kΩ	2.5 ± 0.2	15	_	7.6	16.2	1.0	19.0	ns
				50	_	10.7	19.0	1.0	22.0	
3-state output enable			3.3 ± 0.3	15	_	5.7	11.5	1.0	13.5	
time				50	_	8.1	15.0	1.0	17.0	
			5.0 ± 0.5	15	_	4.2	7.7	1.0	9.0	
				50	_	6.1	9.7	1.0	11.0	
			2.5 ± 0.2	50	_	13.6	17.3	1.0	19.0	
3-state output disable time	t _{pLZ} t _{pHZ}	$R_L = 1 k\Omega$	3.3 ± 0.3	50	_	10.5	14.5	1.0	16.5	ns
	ιрн∠		5.0 ± 0.5	50	_	8.2	9.7	1.0	11.0	
			2.5 ± 0.2	50	_	_	2.0	-	2.0	
Output to output skew	t _{osLH}	(Note 1)	3.3 ± 0.3	50	_	_	1.5	-	1.5	ns
	t _{osHL}		5.0 ± 0.5	50	_	_	1.0	-	1.0	
Input capacitance	C _{IN}		_		_	4	10	_	10	pF
Output capacitance	Cout		_		_	6	_	_	_	pF
Power dissipation capacitance	C _{PD}			(Note 2)	_	25	_	_	_	pF

Note 1: Parameter guaranteed by design.

tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|

Note 2: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

ICC (opr) = CPD·VCC·fIN + ICC/8 (per latch)

And the total CPD when n pcs. of latch operate can be gained by the following equation:

CPD (total) = 13 + 12·n



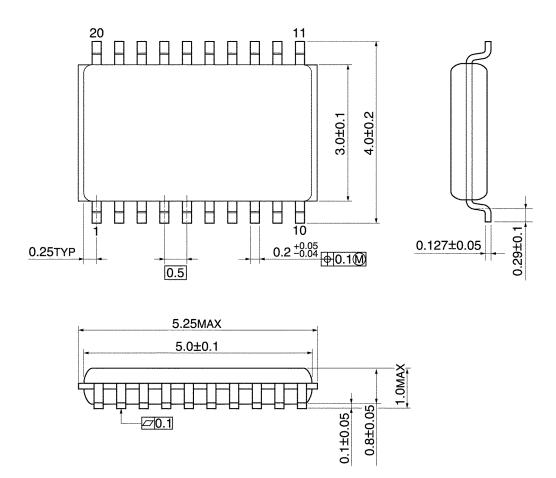
Noise Characteristics (input: tr = tf = 3 ns)

Characteristics	Cumbal	Test Condition		Ta = 25°C		Unit
Characteristics	Symbol		V _{CC} (V)	Тур.	Max	Offic
Quiet output maximum dynamia Vol	Volp	C _L = 50 pF	3.3	0.4	_	V
Quiet output maximum dynamic V _{OL}	VOLP	CL = 90 pr	5.0	8.0	1	v
Quiet output minimum dynamic VOL	Volv	C _L = 50 pF	3.3	-0.1	-	V
Quiet output minimum dynamic VOL		СС = 30 рі	5.0	-0.4	1	V
Minimum high level dynamic input voltage	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage	VILD	C _L = 50 pF	5.0	_	1.5	V



Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)



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